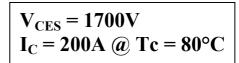
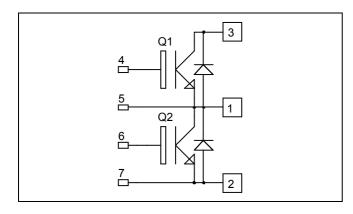


Phase leg Trench + Field Stop IGBT3 Power Module





Application

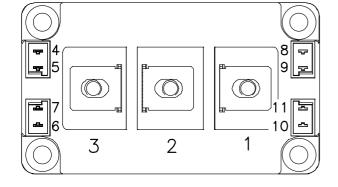
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors



- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
Ţ	Continuous Collector Current	$T_C = 25$ °C	310	
I_{C}	Continuous Collector Current	$T_C = 80$ °C	200	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	400	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	1250	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	400A@1650V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				3	mA
V _{CE(on)}	Collector Emitter on Voltage		$T_j = 25$ °C		2.0	2.5	V
			$T_j = 125$ °C		2.4		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 8 \text{ mA}$		5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$			18		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.6		111
Q_{G}	Gate charge	V _{GE} =±15V, I _C =200A V _{CE} =900V			2.3		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		280		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			80		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$			850		ns
T_{f}	Fall Time	$I_{\rm C} = 200 A$ $R_{\rm G} = 6.8 \Omega$			120		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 900V$ $I_{C} = 200A$ $R_{G} = 6.8\Omega$			300		ns
$T_{\rm r}$	Rise Time				100		
$T_{d(off)}$	Turn-off Delay Time				1000		
T_{f}	Fall Time				200		
Б	Turn On Engrav	$V_{GE} = \pm 15V$	$T_i = 25^{\circ}C$		58		
Eon	Turn On Energy	$V_{Bus} = 900V$	$T_i = 125$ °C		78		mJ
E_{off}	Turn Off Energy	$I_{\rm C} = 200 {\rm A}$	$T_j = 25$ °C		43		1113
-off	Turn On Energy	$R_G = 6.8\Omega$	$T_{i} = 125^{\circ}C$		63		
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; V_{Bus} $t_p \le 10 \mu s$; $T_i = 1$			800		A

Reverse diode ratings and characteristics

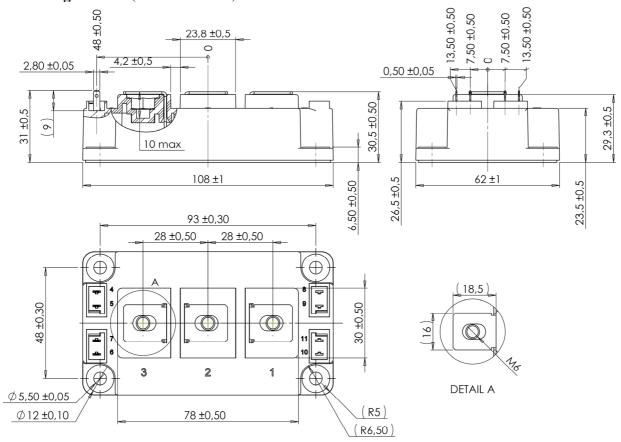
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RRM}	Maximum Reverse Leakage Current	V _R =1700V	$T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$			750 1000	μА
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		200		A
V_{F}	Diode Forward Voltage	$I_F = 200A$	$T_{j} = 25^{\circ}C$ $T_{i} = 125^{\circ}C$		1.8 1.9	2.2	V
t _{rr}	Reverse Recovery Time	$I_F = 200A$ $V_R = 900V$ $di/dt = 3200A/\mu s$	$T_j = 25^{\circ}C$ $T_i = 125^{\circ}C$		385 490		ns
Qrr	Reverse Recovery Charge		$T_{j} = 25^{\circ}C$ $T_{i} = 125^{\circ}C$		56 92		μС
E _{rr}	Reverse Recovery Energy		$T_j = 25^{\circ}C$ $T_i = 125^{\circ}C$		24 48		mJ



Thermal and package characteristics

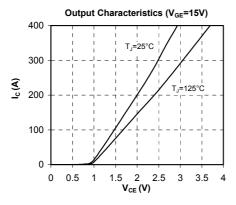
Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.10	°C/W
N _{th} JC Junction to Case 1 hermal Resistance		Diode			0.16	C/ VV	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range -40					150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		125	
Torque	Mounting torque	For terminals	M6	3		5	N.m
		To Heatsink	M6	3		5	18.111
Wt	Package Weight					350	g

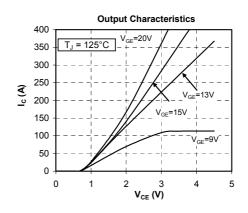
$D3\ Package\ outline\ ({\rm dimensions\ in\ mm})$

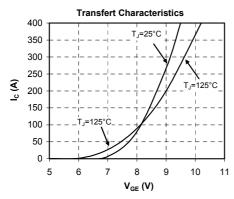


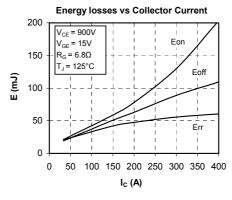


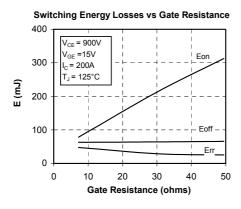
Typical Performance Curve

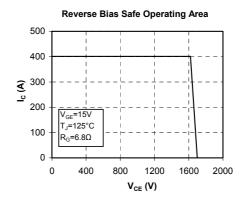


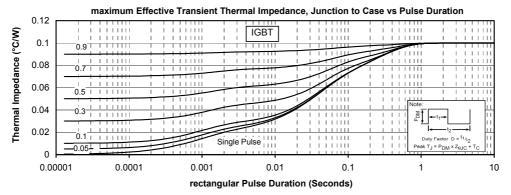






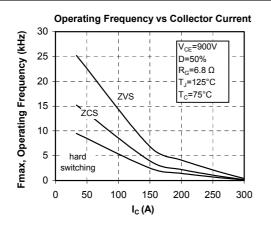


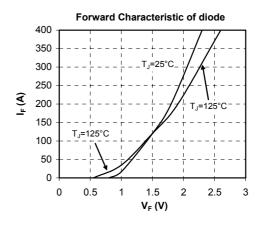


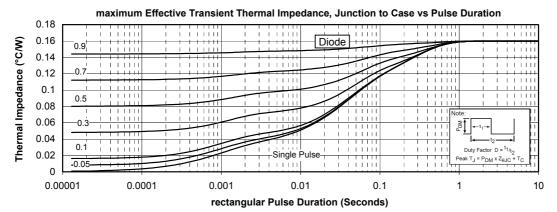


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